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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of: ) Attorney Docket: 4425-154

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LAI ET AL.

) Group Art Unit: 2823

)

Serial No.: 09/888,494

) Examiner: Long Pham

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Filed: June 26, 2001

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For: METHOD FOR FORMING A METAL OXIDE SEMICONDUCTOR  
TYPE FIELD EFFECT TRANSISTOR

AMENDMENT

Honorable Commissioner for Patents  
Washington, D.C. 20231

Sir:

This paper is in response to the Official Action dated July 9, 2002.  
In that Official Action, Claims 1-18 are rejected under 35 U.S.C.  
§103(a). Kindly amend the application in accordance with the following  
particulars: